

# EPIGAP Optronik GmbH

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## Data Sheet

page 1 of 2

### IR photodiode

EOPD-1300-5-0.3

Rev. 03, 2017

Radiation	Type	Technology	Case
Infrared	Planar	InGaAs/InP	5 mm plastic

Description:	
	<p>InGaAs - photodiode mounted in standard 5 mm package without standoff. High spectral sensitivity in the infrared range (NIR, SWIR).</p>
Applications:	
<p>Optical communications, safety equipment, light barriers</p>	

All dimensions in mm

### Maximum Ratings

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

Parameter	Symbol	Value	Unit
Active area, diameter	$A\phi$	300	$\mu\text{m}$
Temperature coefficient of photocurrent	$TC(I_{ph})$	7.4	%/K
Operating temperature range	$T_{amb}$	-40 to +85	$^{\circ}\text{C}$
Storage temperature range	$T_{stg}$	-40 to +100	$^{\circ}\text{C}$

### Optical and Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test conditions	Symbol	Min	Typ	Max	Unit
Breakdown voltage*	$I_R = 10 \mu\text{A}$	$V_R$	5			V
Dark current	$V_R = 5 \text{ V}$	$I_D$		15	40	$\mu\text{A}$
Peak sensitivity wavelength	$V_R = 0 \text{ V}$	$\lambda_p$		1600		nm
Responsivity at 1300 nm	$V_R = 0 \text{ V}$	$S_\lambda$		0.9		A/W
Sensitivity range at 10%	$V_R = 0 \text{ V}$	$\lambda_{min}, \lambda_{max}$	800		1750	nm
Spectral bandwidth at 50%	$V_R = 0 \text{ V}$	$\Delta\lambda_{0.5}$		680		nm
Shunt resistance	$V_R = 10 \text{ mV}$	$R_{SH}$	3	5		$\text{G}\Omega$
Noise equivalent power	$\lambda = 1300 \text{ nm}$	NEP		$4 \times 10^{-15}$		$\text{W}/\sqrt{\text{Hz}}$
Specific detectivity	$\lambda = 1300 \text{ nm}$	D		$4.5 \times 10^{12}$		$\text{cm} \cdot \sqrt{\text{Hz}} \cdot \text{W}^{-1}$
Junction capacitance	$V_R = 0 \text{ V}$	$C_J$		11		pF
Photocurrent at $\lambda = 1300 \text{ nm}^*$	$V_R = 0 \text{ V}$	$I_{ph}$		0.95		$\mu\text{A}$
	$E_e = 1 \text{ mW}/\text{cm}^2$					

\*for information only



We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer.

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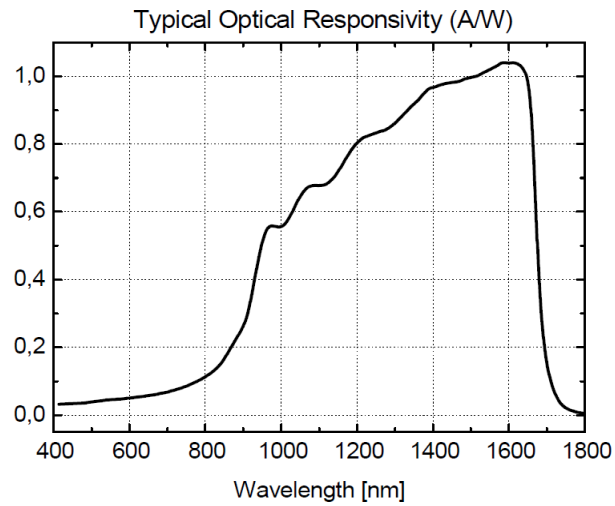


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page 2 of 2  
Rev. 03, 2017



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